

2MBI600VD-060-50

IGBT Modules

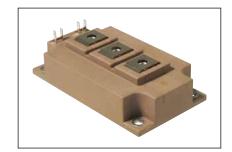
IGBT MODULE (V series) 600V / 600A / 2 in one package

■ Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



■ Maximum Ratings and Characteristics

■ Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
Collector-Emitter voltage		Vces			600	V	
Gate-Emitter voltage		V _{GES}			±20	V	
Collector current		Ic	Continuous	Tc=80°C	600		
		Ic pulse	1ms	Tc=80°C	1200		
		-lc			600		
		-lc pulse	1ms	1ms			
Collector power dissipation		Pc	1 device		2940	W	
Junction temperature		Tj			175		
Operating junction temperature (under switching conditions)		T _{jop}			150	°C	
Case temperature		Tc			125		
Storage temperature		Tstg			-40 ~ +125		
Isolation voltage between terminal and copper base (*1)		Viso	AC : 1min.		2500	VAC	
Screw torque	Mounting (*2)				6.0	NI	
	Terminals (*3)	1-			5.0	N m	

Note *1: All terminals should be connected together during the test.

Note *2: Recommendable Value : 3.0-6.0 Nm (M5 or M6) Note *3: Recommendable Value : 2.5-5.0 Nm (M6)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

ama	Symbole	Conditions	Sanditions.		Characteristics		I I mit m	
ems	Symbols	Conditions		min.	typ.	max.	Units	
Zero gate voltage collector current	Ices	$V_{GE} = 0V, V_{CE} = 600V$		-	-	2.0	mA	
Gate-Emitter leakage current	Iges	$V_{CE} = 0V$, $V_{GE} = \pm 20V$		-	-	800	nA	
Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 600mA		6.2	6.7	7.2	V	
	.,	V _{GE} = 15V I _C = 600A	Tj=25°C	-	1.85	2.30	V	
	V _{CE (sat)} (terminal)		Tj=125°C	-	2.15	-		
Collector-Emitter saturation voltage	(terrillial)		Tj=150°C	-	2.35	-		
Collector-Emitter Saturation voltage	VCE (sat)		Tj=25°C	-	1.60	2.05		
			Tj=125°C	-	1.90	-		
	(chip)		Tj=150°C	-	2.00	-		
Internal gate resistance	R _{g(int)}	R _{g(int)} -		-	1.5	-	Ω	
Input capacitance	Cies	$V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$		-	38.9	-	nF	
Input capacitance Turn-on time	ton			-	0.75	-		
Turn-on time	tr	$V_{CC} = 300V$, $I_C = 600A$ $V_{GE} = \pm 15V$, $R_G = 2.2\Omega$ Tj = 150°C, Ls = 30nH		-	0.40	-	μsec	
	tr (i)			-	0.15	-		
Turn-off time	toff			-	0.75	-		
Turn-on time	tf			-	0.07	-		
	V _F (terminal)	V _{GE} = 0V I _F = 600A	Tj=25°C	-	1.70	2.25	V	
Famusad as valtees			Tj=125°C	-	1.60	-		
			Tj=150°C	-	1.57	-		
Forward on voltage	V		Tj=25°C	-	1.60	1.85		
	V _F		Tj=125°C	-	1.50	-		
	(chip)		Tj=150°C	-	1.47	-		
Reverse recovery time	trr	I _F = 600A	<u> </u>	-	0.25	-	usec	

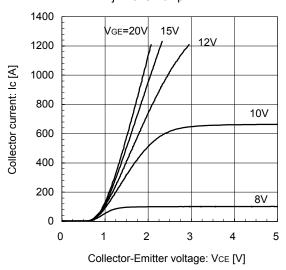
Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
items			min.	typ.	max.	Units
Thermal resistance (1device)	Rth(j-c)	IGBT	-	-	0.051	°C/W
Thermal resistance (Tuevice)		FWD	-	-	0.088	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.0125	-	

Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

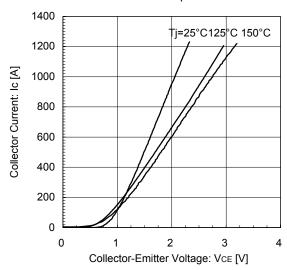
■ Characteristics (Representative)

Collector current vs. Collector-Emitter voltage (typ.) Tj= 25°C / chip

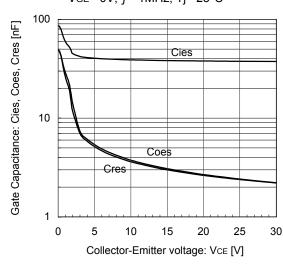


Collector current vs. Collector-Emitter voltage (typ.)

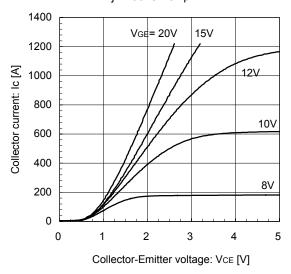
VGE= 15V / chip



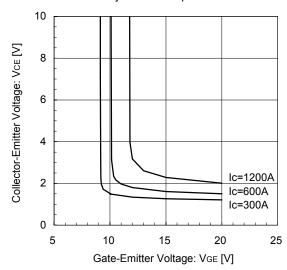
Gate Capacitance vs. Collector-Emitter Voltage VGE= 0V, f= 1MHz, Tj= 25°C

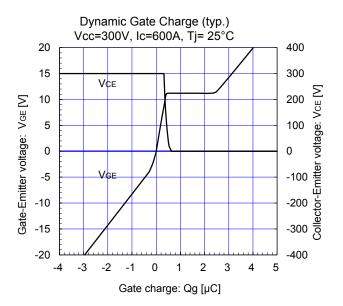


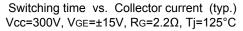
Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip

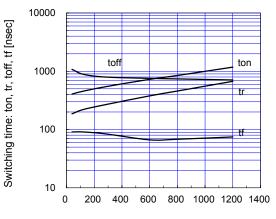


Collector-Emitter voltage vs. Gate-Emitter voltage Tj= 25°C / chip



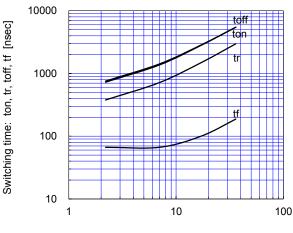






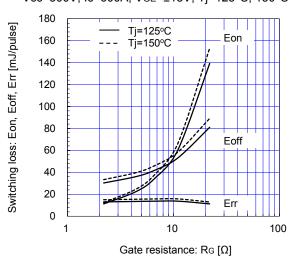
Collector current: Ic [A]

Switching time vs. Gate resistance (typ.) Vcc=300V, Ic=600A, VgE=±15V, Ti=125°C

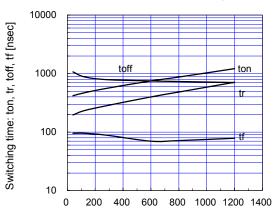


Gate resistance: R_G [Ω]

Switching loss vs. Gate resistance (typ.) Vcc=300V, Ic=600A, VGE=±15V, Tj=125°C, 150°C

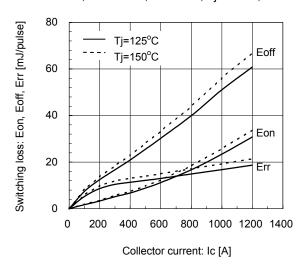


Switching time vs. Collector current (typ.) Vcc=300V, $VgE=\pm15V$, $Rg=2.2\Omega$, Tj=150°C

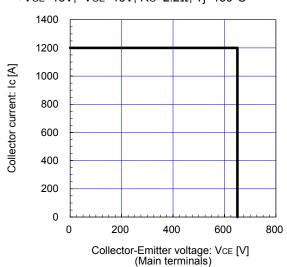


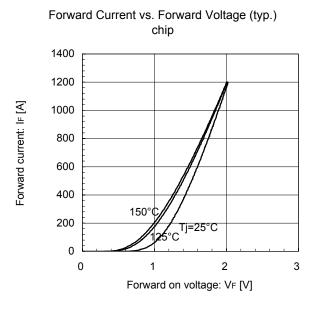
Collector current: Ic [A]

Switching loss vs. Collector current (typ.) Vcc=300V, $VGE=\pm15V$, $RG=2.2\Omega$, $Tj=125^{\circ}C$, $150^{\circ}C$

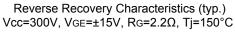


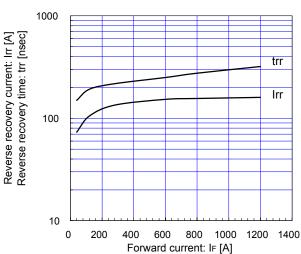
Reverse bias safe operating area (max.) +VGE=15V, -VGE=15V, $RG=2.2\Omega$, $Tj=150^{\circ}C$

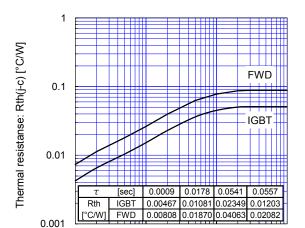




Forward current: IF [A]







0.01

0.001

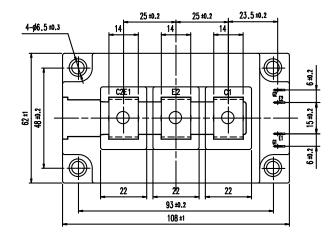
Transient Thermal Resistance (max.)

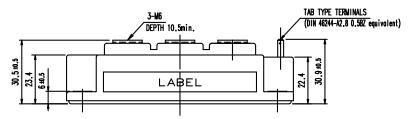
Pulse Width: Pw [sec]

0.1

http://www.fujielectric.com/products/semiconductor/

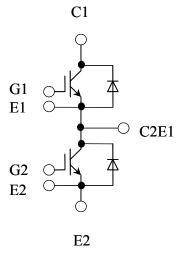
■ Outline Drawings (Unit: mm)





Weight: 370g (typ.)

■ Equivalent Circuit



http://www.fujielectric.com/products/semiconductor/

WARNING

- 1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of December 2014.

 The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sur to obtain the latest specifications.
- 2. All applications described in this Catalog exemplify the use of Fuji's products for your reference only. No right or license, either express or implied, under any patent, copyright, trade secret or other intellectual property right owned by Fuji Electric Co., Ltd. is (or shall be deemed) granted. Fuji Electric Co., Ltd. makes no representation or warranty, whether express or implied, relating to the infringement or alleged infringement of other's intellectual property rights which may arise from the use of the applications described herein.
- 3. Although Fuji Electric Co., Ltd. is enhancing product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury, fire, or other problem if any of the products become faulty. It is recommended to make your design failsafe, flame retardant, and free of malfunction.
- 4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
 - Computers
- OA equipment
- Communications equipment (terminal devices)
- Measurement equipment

- Machine tools
- Audiovisual equipment
- Electrical home appliances Pe
- 5. If you need to use a product in this Catalog for equipment requiring higher reliability than normal, such as for the equipment listed below, it is imperative to contact Fuji Electric Co., Ltd. to obtain prior approval. When using these products for such equipment, take adequate measures such as a backup system to prevent the equipment from malfunctioning even if a Fuji's product incorporated in the equipment becomes faulty.
- Transportation equipment (mounted on cars and ships)
- Traffic-signal control equipment
- Emergency equipment for responding to disasters and anti-burglary devices
- Medical equipment

- Trunk communications equipment
- Gas leakage detectors with an auto-shut-off feature
- Safety devices
- 6. Do not use products in this Catalog for the equipment requiring strict reliability such as the following and equivalents to strategic equipment (without limitation).
- Space equipmentSubmarine repeater equipment
- Aeronautic equipment
- Nuclear control equipment
- 7. Copyright ©1996-2014 by Fuji Electric Co., Ltd. All rights reserved.

No part of this Catalog may be reproduced in any form or by any means without the express permission of Fuji Electric Co., Ltd.

8. If you have any question about any portion in this Catalog, ask Fuji Electric Co., Ltd. or its sales agents before using the product.

Neither Fuji Electric Co., Ltd. nor its agents shall be liable for any injury caused by any use of the products not in accordance with instructions set forth herein.